

CPL24

(CPL20L8, CPL20R4, CPL20R6, CPL20R8 and CPL20L10)

CMOS Programmable Logic Array 24-Pin Series

FEATURES/BENEFITS

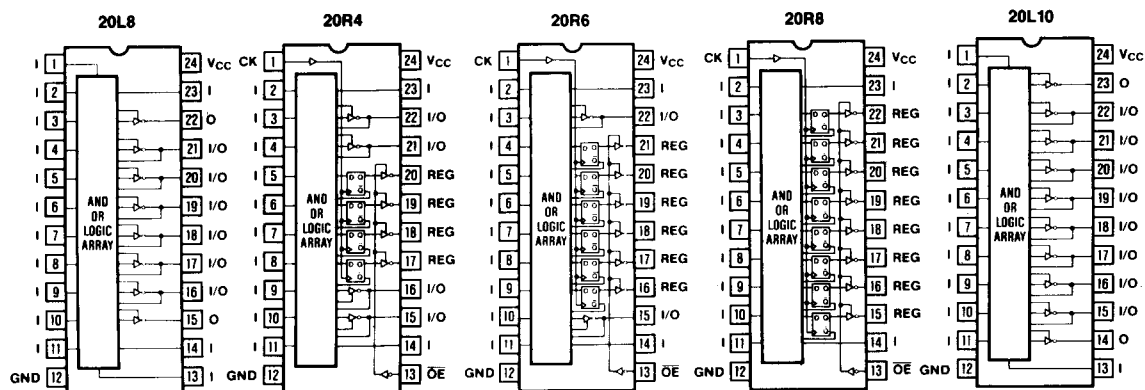
- High-speed CMOS equivalent to Bipolar PAL
- CMOS UV-erasable EPROM cell to allow reprogrammability
- Low power (35 mA Max. I_{CC}) and Standard (70 mA Max. I_{CC}) versions
- Four speed grades ($t_{PD} = 15\text{ns Max}$, $t_{PD} = 20\text{ns Max}$, $t_{PD} = 25\text{ns Max}$, and $t_{PD} = 35\text{ns Max}$)
- Available over both commercial and industrial temperature ranges
- >2000V ESD input and output protection
- 100% functional and AC tested
- 100% programming tested
- Programmable security bit to prevent pattern duplication
- Register preload for register initialization
- Programmable three-state outputs

DESCRIPTION

The CPL24 Series devices are high-speed, UV-erasable, electrically programmable CMOS logic replacements of the Bipolar 24-pin PAL20R8 family and PAL20L10 devices. They utilize the familiar sum-of-products form (AND array followed by an OR array) allowing the user to customize logic to his/her needs.

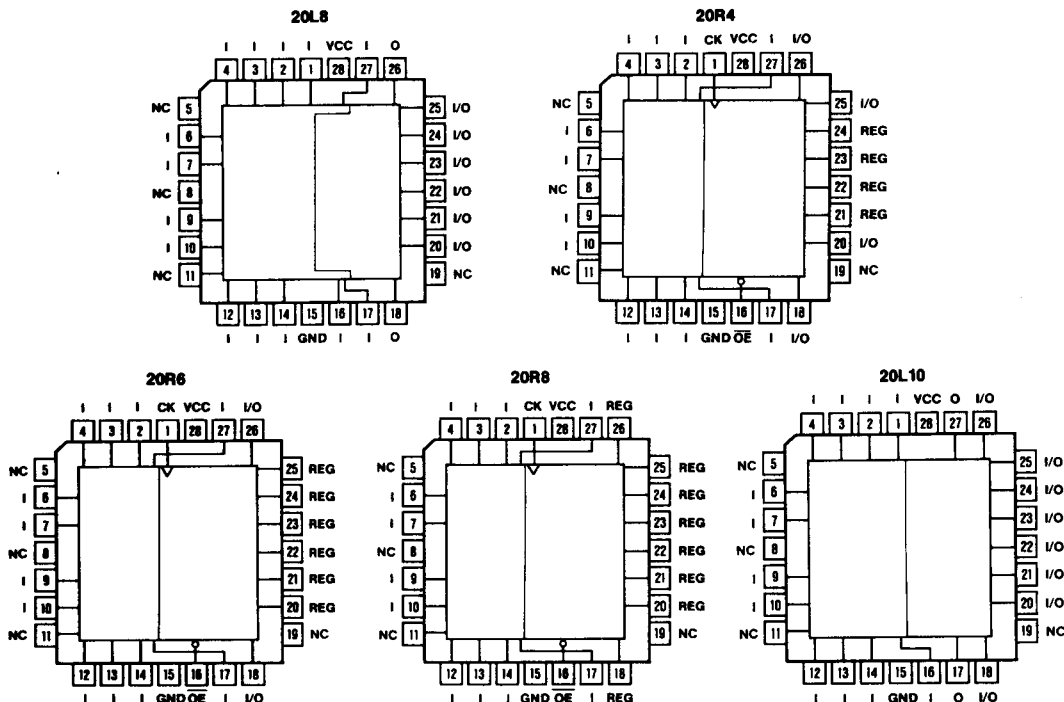
Five devices are offered in the CPL24 Series. They are: the CPL20L10, the CPL20L8, the CPL20R4, the CPL20R6, and the CPL20R8. Each of these devices has 20 array inputs. The CPL20L10 has 10 outputs and the others have 8 outputs. All the outputs to the CPL20L8 and CPL20L10 are combinatorial, while all outputs to the CPL20R8 are registered. In contrast, the CPL20R4 has 4 registered and 4 combinatorial outputs and the CPL20R6 has 6 registered and 2 combinatorial outputs. Each combinatorial output in the CPL20R6 and CPL20R4 devices serves as an I/O pin. The CPL20L10 device has 8 I/O pins, and the CPL20L8 device has 6 I/O pins.

LOGIC SYMBOLS AND PINOUTS



DIP PACKAGES

LOGIC SYMBOLS AND PINOUTS (Continued)



PLCC PACKAGES (NL)

DESCRIPTION (Continued)

The CPL devices are manufactured using a 1.2 micron EPROM technology which offers low power dissipation (45/70 mA maximum I_{CC}) combined with high performance (15ns maximum propagation delay). Because the CPL devices are erasable, they can be thoroughly tested for programming, functional and AC integrity, resulting in high-reliability and 100% programming yields.

The CPL24 devices are housed in 24-pin plastic DIP, and windowed Cerdip packages, as well as a 28-pin PLCC package. The windowed Cerdip package allows the user to erase the CPL device using UV light, and later to reprogram it with a different pattern. The plastic DIP, and PLCC devices are one-time-programmable (OTP) and may not be erased.

Register Preload

The register preload feature of the CPL24 Series allows output pins to be loaded with arbitrary states, making functional testing easier than ever.

Security Bit

All CPL24 devices feature a security bit. The security bit allows the user to protect his/her design against unauthorized duplication. When the security bit is set, the contents of the programmable-cell array may not be accessed in Read or Verify modes. Since the CPL devices do not have visible fuses, they offer enhanced security over what is available in bipolar PAL devices.

Test Array

Another feature of the devices in the CPL24 Series is the on-chip test array. It is programmed for final functional and AC testing of the devices after they have been packaged (even if the security bits have been programmed). In the normal operation of the device, the test arrays are not accessed. In the test mode of operation, only the input terms in the shaded portion of the functional block diagram are accessed. The test array facilitates high-reliability as well as simple and short testing.

ERASURE (windowed-CERDIP only)

The CPL devices will erase by light at wavelengths of under 4000 Angstroms. The window must be covered by an opaque label to prevent erasure by exposure to sunlight or fluorescent lighting.

Recommended dose of ultraviolet light for erasure:

Wavelength of 2537 Angstroms
(minimum dose -- 25 Wsec/cm²)

If an ultraviolet lamp with a 12mW/cm² power rating is used, 30 to 35 minutes of erasure time will suffice. The lamp must be closer than 1 inch from the window to guarantee optimal erasing conditions. Exposure to high intensity UV light for an extended period of time may cause permanent damage to the CPL devices. The maximum dosage recommended is 7250 Wsec/cm².

CPL24 ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{CC}	-0.5 to +7.0	V
DC Input Voltage	V _{IN} ($ I_{IN} \leq 20\text{mA}$)	-3.0 to +7.0	V
Off-State DC Output Voltage	V _O	-0.5 to V _{CC} + 0.5	V
DC Programming Voltage	V _{PP}	14.0	V
Storage Temperature	T _{STG}	-65 to +150	°C
Power Dissipation per Package	P _D (Note 2)	500	mW

Note 1: Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only, and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

Note 2: Power dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

RECOMMENDED OPERATING CONDITIONS For all CPL24, except CPL24-15

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{CC}	4.5 to 5.5	V
DC Input and Output (Off-State) Voltages	V _{IN} , V _O (Note 3)	0 to V _{CC}	V
Operating Temperature Range, Commercial	T _A	0 to +70	°C
Operating Temperature Range, Industrial	T _A	-40 to +105	°C

RECOMMENDED OPERATING CONDITIONS For CPL24-15

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{CC}	4.75 to 5.25	V
DC Input and Output (Off-State) Voltages	V _{IN} , V _O (Note 3)	0 to V _{CC}	V
Operating Temperature Range, Commercial	T _A	0 to +70	°C
Operating Temperature Range, Industrial	T _A	-40 to +105	°C

Note 3: Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND).

DC ELECTRICAL CHARACTERISTICS

Over Recommended Operating Conditions

Parameter	Symbol	Test Conditions		Min	Max	Unit
Low Level Input Voltage	V_{IL}				0.8	V
High Level Input Voltage	V_{IH}			2.0		V
Input Current	I_{IN}	$0 < V_{IN} < V_{CC}$		-10	10	μA
Low Level Output Voltage	V_{OL}	$V_{CC} = \text{Min}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 24\text{mA}$		0.5	V
High Level Output Voltage	V_{OH}	$V_{CC} = \text{Min}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -3.2\text{mA}$	2.4		V
Off-State Output Leakage Current	I_{OZL}	$V_{CC} = \text{Max},$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_O = 0.4\text{V}$		-100	μA
	I_{OZH}		$V_O = 2.4\text{V}$		100	
Power Supply Current	I_{CC}	All inputs = GND $V_{CC} = \text{Max}$ $I_{OUT} = 0\text{mA}$	"L" STC "L-15"		35 70 45	mA mA mA

Note 4: These are absolute values with respect to device ground. The applied voltage plus overshoots due to system and/or tester noise must not exceed these worst-case values.

CPL24 AC ELECTRICAL CHARACTERISTICS, CPL20L10 only

Over Recommended Operating Conditions (Note 5)

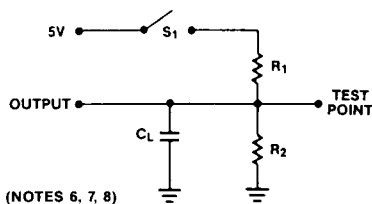
Parameter	Symbol	Commercial (0 to +70°C)								Industrial (-40 to +105°C)								Unit
		-15		-20		-25		-30		-15*		-20		-25		-30		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Input or Feedback to Non-Registered Output, 20L10	t _{PD}		15		20		25		30		15		20		25		30	ns
Input to Output Enabled, 20L10	t _{PZX}		15		20		25		30		15		20		25		30	ns
Input to Output Disabled, 20L10	t _{PXZ}		15		20		25		30		15		20		25		30	ns
Clock Width (High or Low)	t _W	10		15		15		18		10		15		15		18		ns
Clock Period	t _P	24		30		35		40		24		30		35		40		ns
Maximum Frequency	f _{MAX}	41.6		33.3		28.5		25		41.6		33.3		28.5		25		MHz

CPL24 AC ELECTRICAL CHARACTERISTICS, except CPL20L10 Over Recommended Operating Conditions (Note 5)

Parameter	Symbol	Commercial (0 to +70°C)								Industrial (-40 to +105°C)								Unit
		-15		-20		-25		-35		-15		-20		-25		-35		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Input or Feedback to Non-Registered Output, 20R6, 20R4, 20L8	t _{PD}		15		20		25		35		15		20		25		35	ns
Clock to Registered Output or Feedback, 20R8, 20R6, 20R4	t _{CO}		12		15		15		25		12		15		15		25	ns
Pin 13 to Output Enabled, 20R8, 20R6, 20R4	t _{PZX13}		12		15		20		25		12		15		20		25	ns
Pin 13 to Output Disabled, 20R8, 20R6, 20R4	t _{PXZ13}		12		15		20		25		12		15		20		25	ns
Input to Output Enabled, 20R6, 20R4, 20L8	t _{PZX}		15		20		25		35		15		20		25		35	ns
Input to Output Disabled, 20R6, 20R4, 20L8	t _{PXZ}		15		20		25		35		15		20		25		35	ns
Setup Time from Input or Feedback to Clock, 20R8, 20R6, 20R4	t _{SU}	12		15		20		30		12		20		20		30		ns
Hold Time, 20R8, 20R6, 20R4	t _H	0		0		0		0		0		0		0		0		ns
Clock Width (High or Low)	t _W	10		15		15		20		10		15		15		20		ns
Clock Period	t _P	24		30		35		55		24		30		35		55		ns
Maximum Frequency	f _{MAX}	41.6		33.3		28.5		18		41.6		33.3		28.5		18		MHz

Note 5: Input rise and fall times (10% to 90% of V_{CC}): $t_r = t_f \leq 6$ ns.

AC Test Circuit



Resistor Values (Ω)

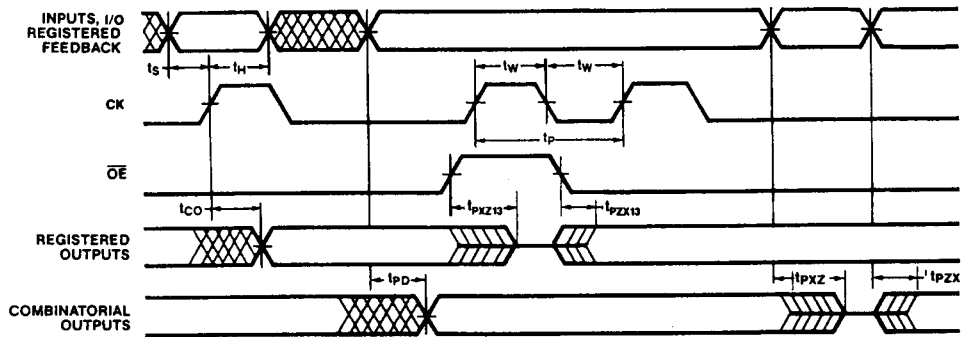
R1	R2
200	390

Note 6: C_L includes load and test jig capacitance.

Note 7: t_{PD} is tested with switch S_1 closed and $C_L = 50$ pF.

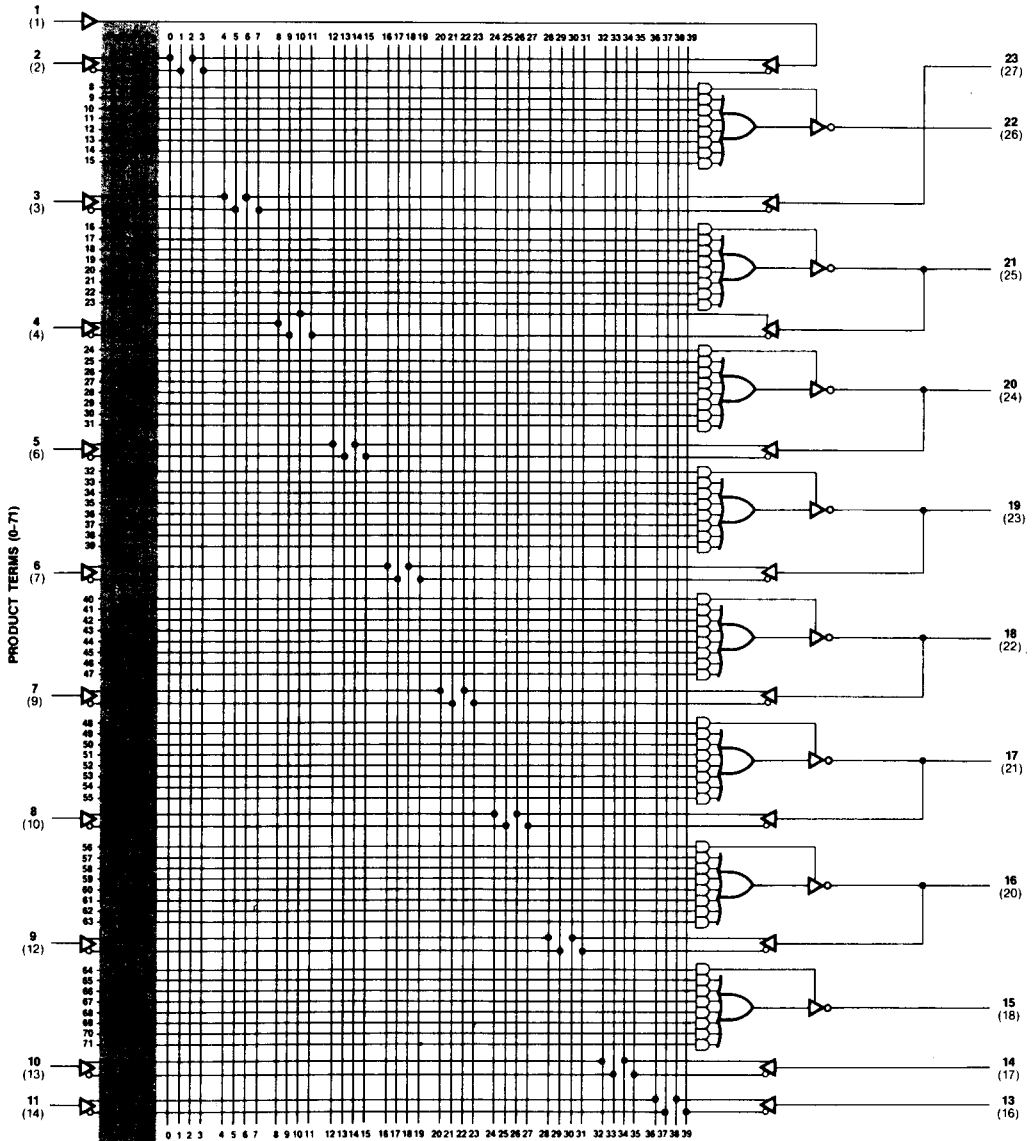
Note 8: For 3-State outputs, output enable times are tested with $C_L = 50$ pF to the 1.5V level; S_1 is open for high impedance to HIGH tests and closed for high impedance to LOW tests. Output disable times are tested with $C_L = 5$ pF. HIGH to high impedance tests are made to an output voltage of $V_{OH} - 0.5$ V with S_1 open; LOW to high impedance tests are made to the $V_{OL} = 0.5$ V level with S_1 closed.

CPL24 WAVEFORMS



CPL24 FUNCTIONAL LOGIC DIAGRAMS (Continued)
DIP AND PLCC PINOUTS

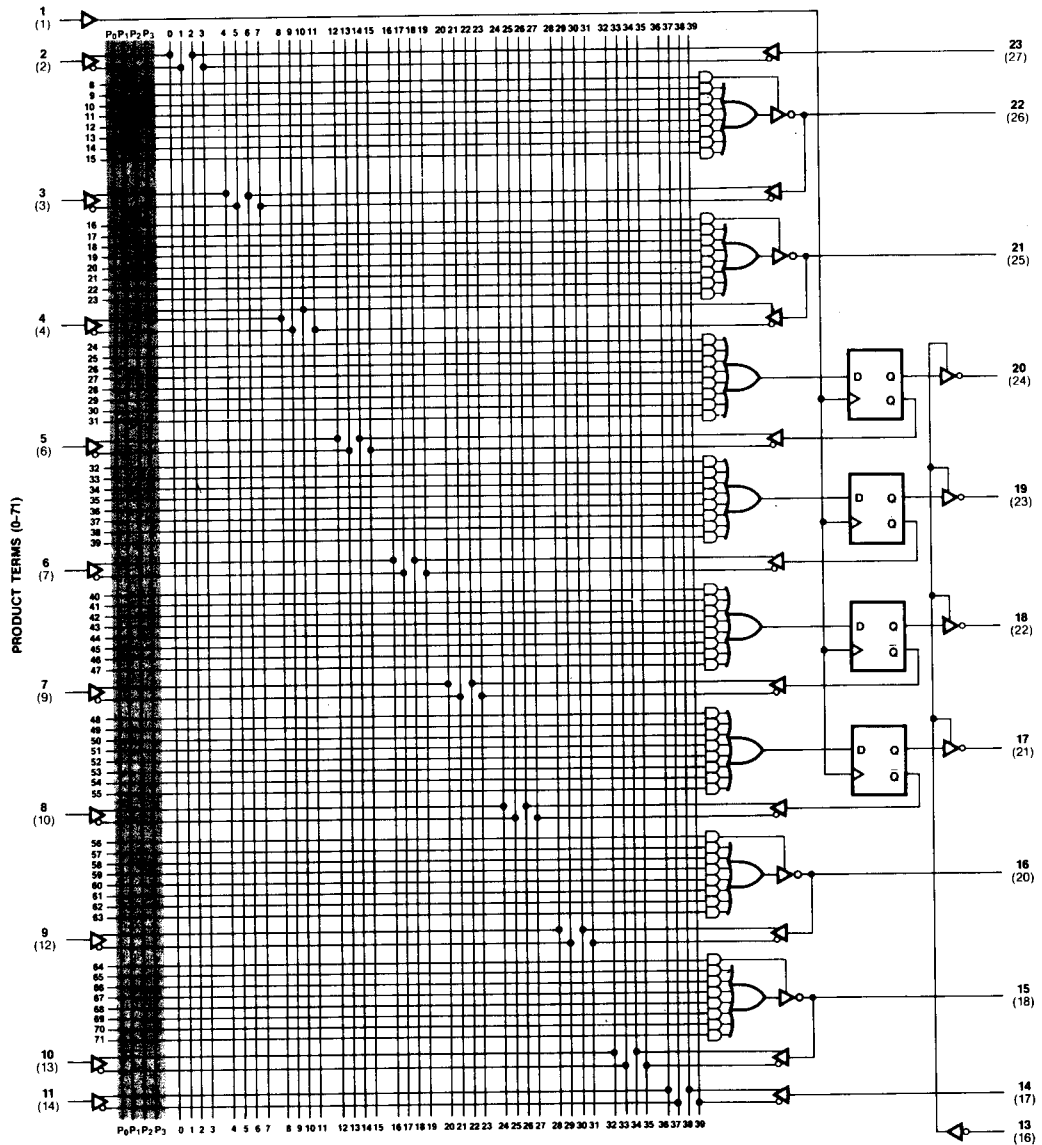
CPL20L8
 INPUTS (0-39)



3

CPL24 FUNCTIONAL LOGIC DIAGRAMS (Continued)
DIP AND PLCC PINOUTS

CPL20R4
 INPUTS (0-39)

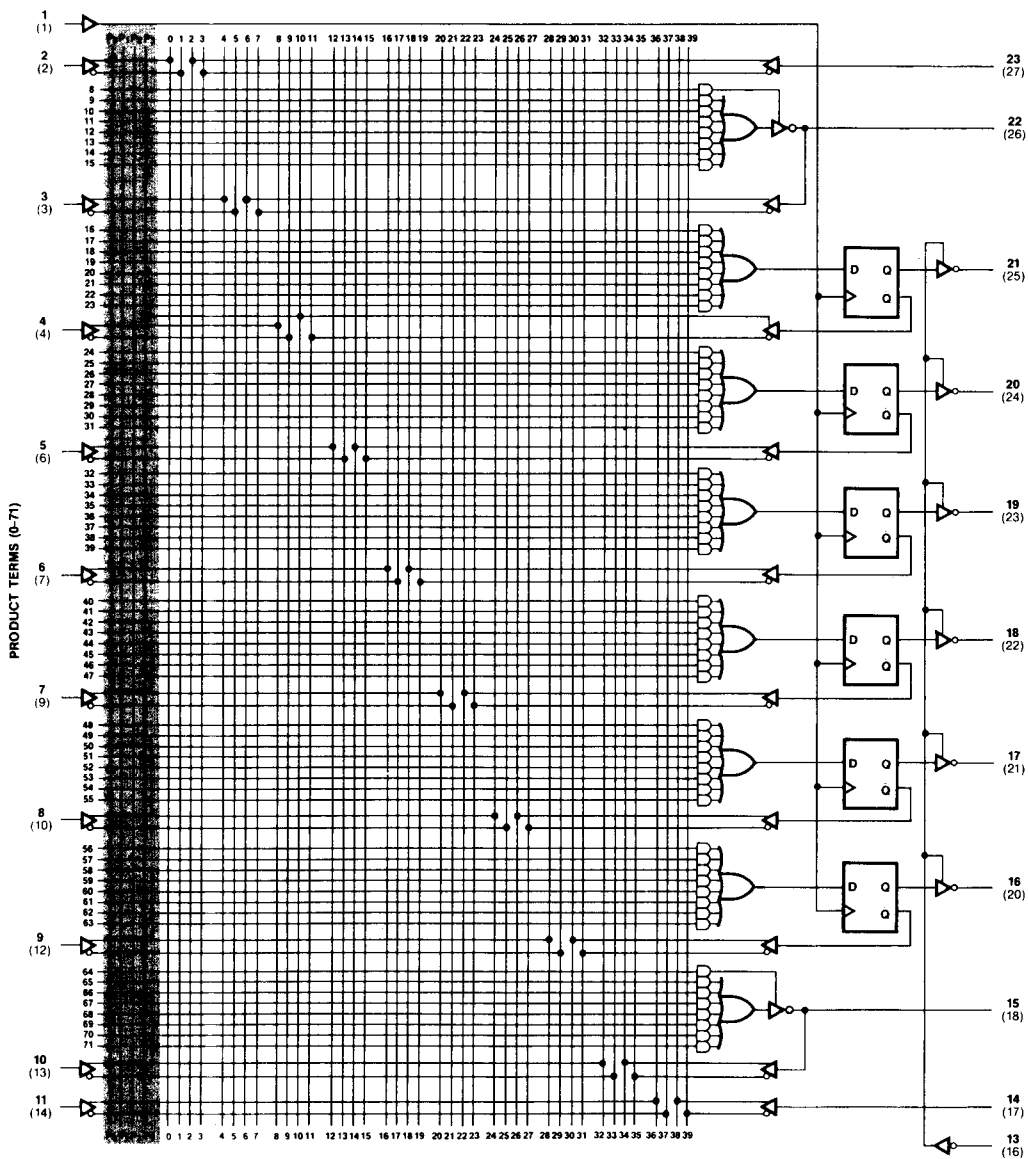


CPL24 FUNCTIONAL LOGIC DIAGRAMS (Continued)

DIP AND PLCC PINOUTS

CPL20R6

INPUTS (0-39)

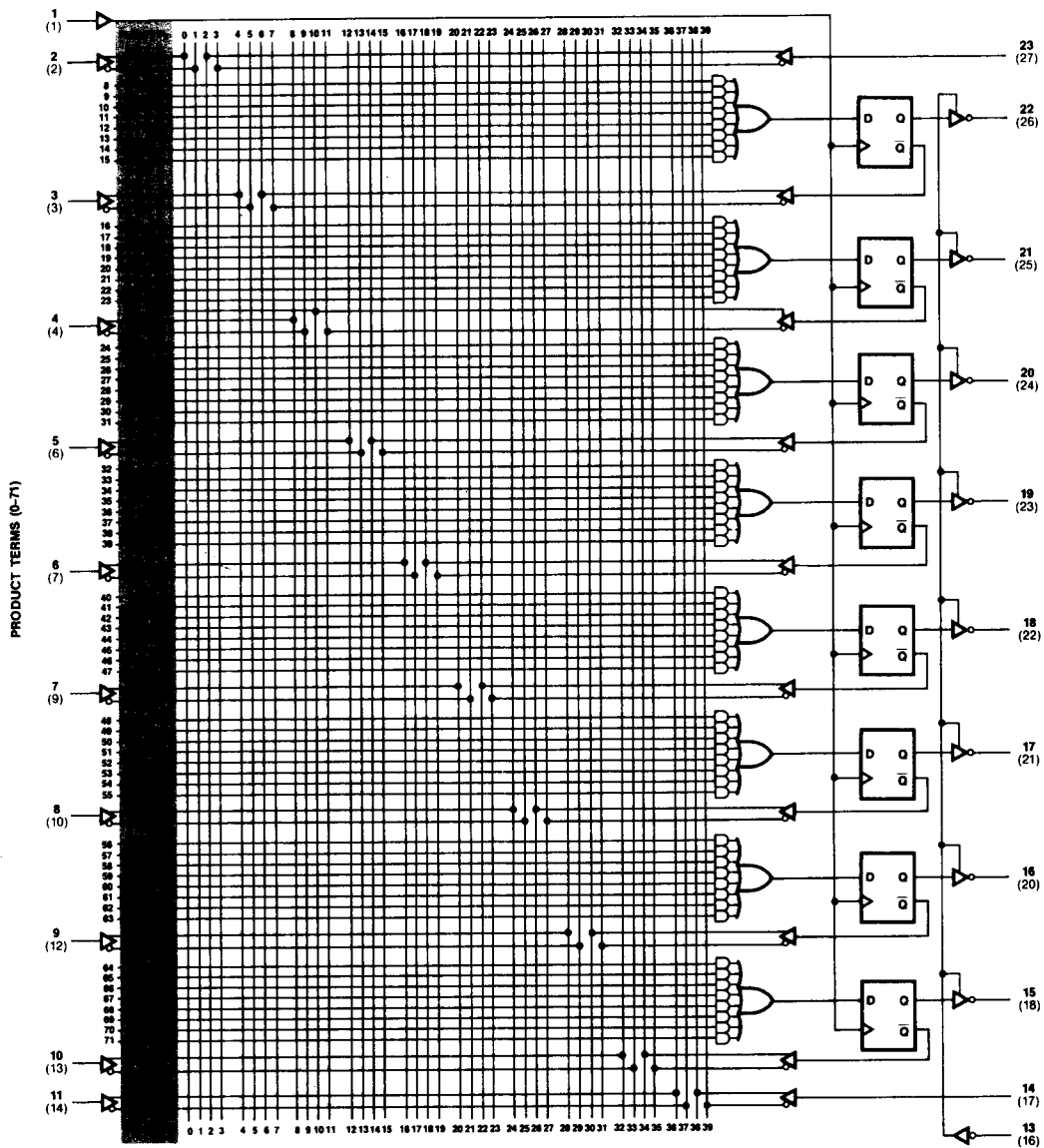


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CPL24 FUNCTIONAL LOGIC DIAGRAMS (Continued)
DIP AND PLCC PINOUTS

CPL20R8

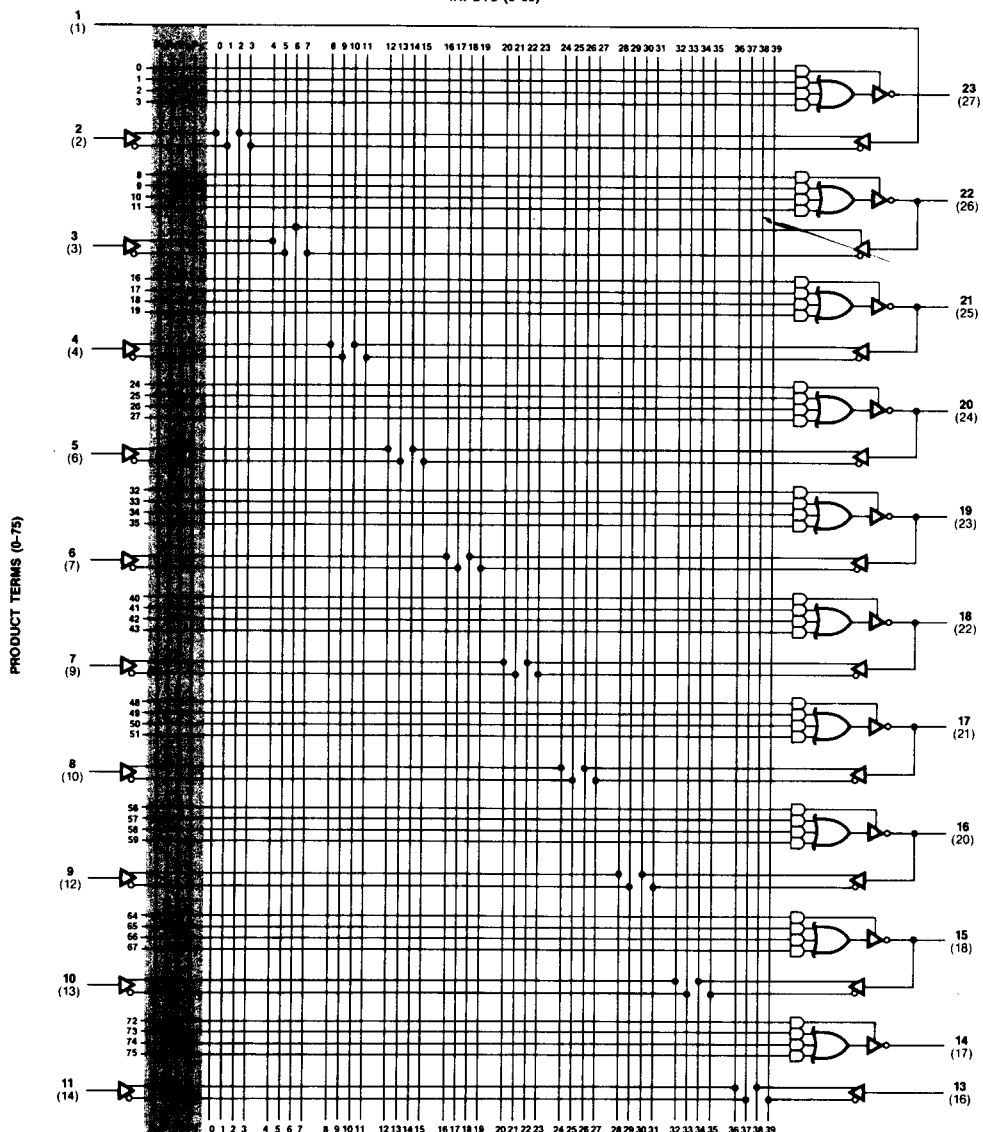
INPUTS (0-39)



CPL24 FUNCTIONAL LOGIC DIAGRAMS DIP AND PLCC PINOUTS

CPL20L10

INPUTS (0-39)



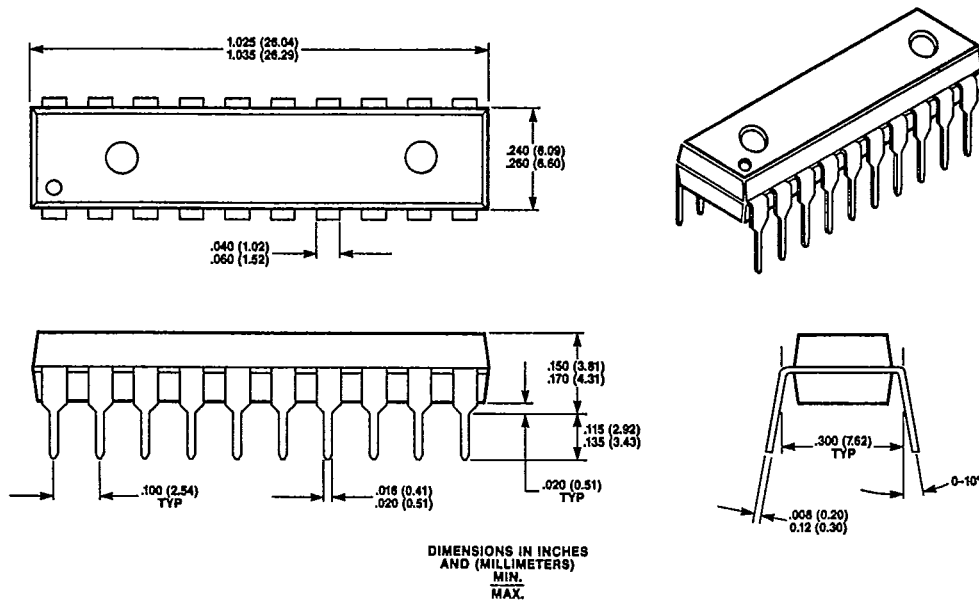
3

7964142 SAMSUNG SEMICONDUCTOR INC

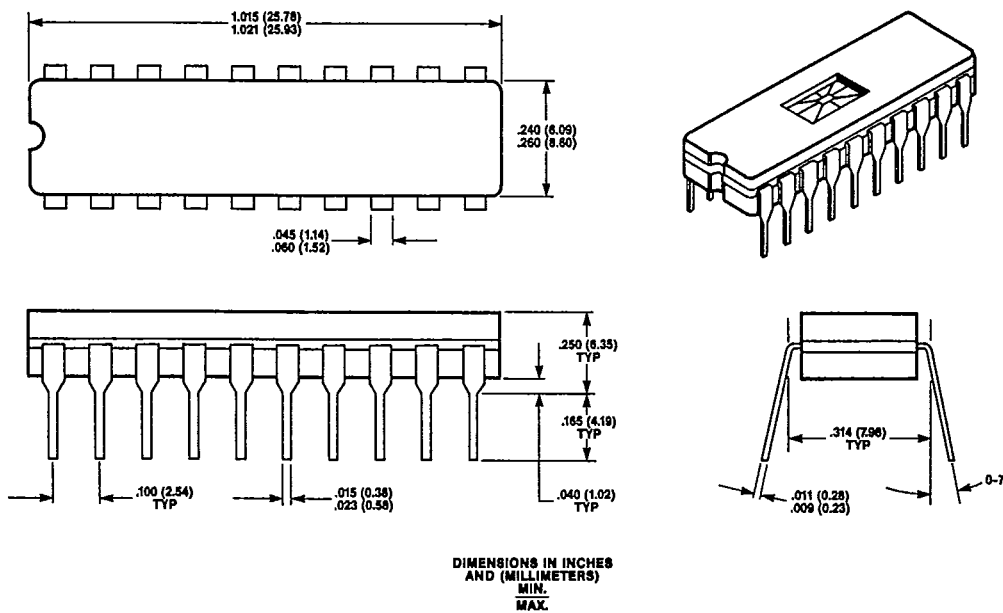
02E 06715 D =

20 PIN PLASTIC DIP

T-90-20



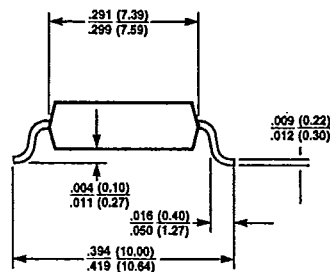
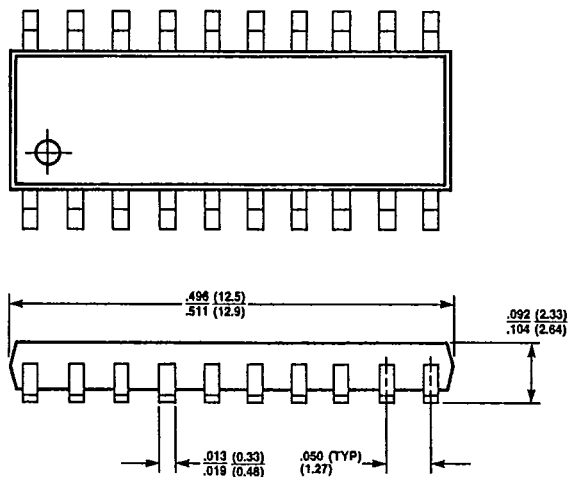
20 PIN WINDOWED CERDIP



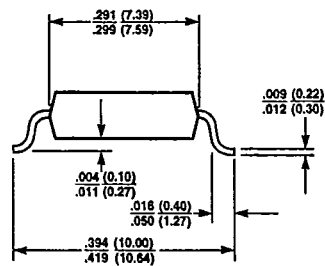
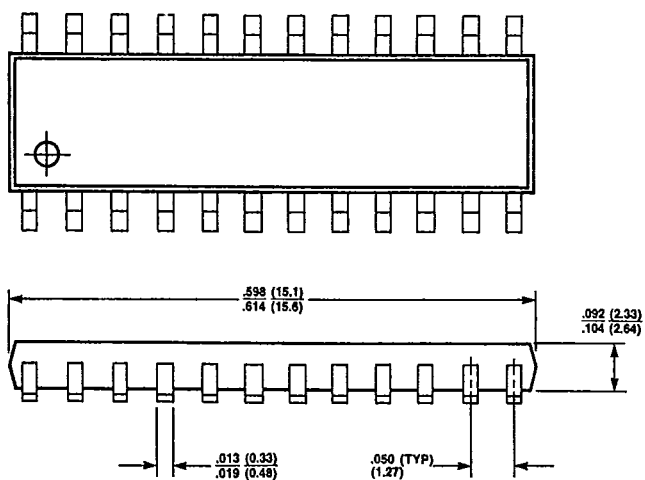
7

T-90-20

20 PIN SOIC

DIMENSIONS IN INCHES AND (MILLIMETERS)
MIN.
MAX.

24 PIN SOIC

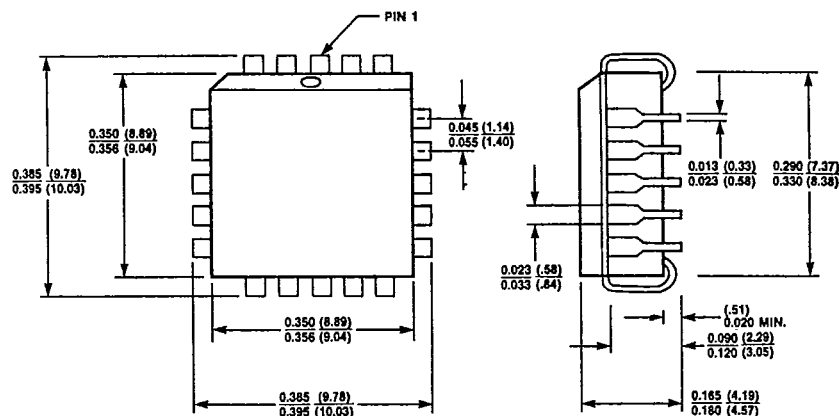
DIMENSIONS IN INCHES AND (MILLIMETERS)
MIN.
MAX.

7964142 SAMSUNG SEMICONDUCTOR INC

02E 06718 D

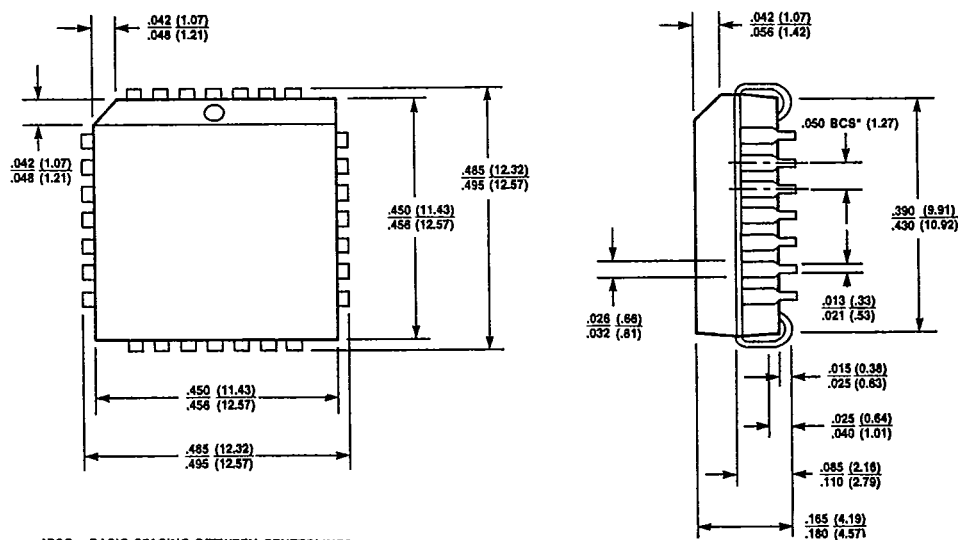
20 PIN PLCC

T-90-20



DIMENSIONS IN INCHES AND (MILLIMETERS)
MIN.
MAX.

28 PIN PLCC



*BSC = BASIC SPACING BETWEEN CENTERLINES

DIMENSIONS IN INCHES AND (MILLIMETERS)
MIN.
MAX.

